

40V N-Channel Enhancement Mode MOSFET

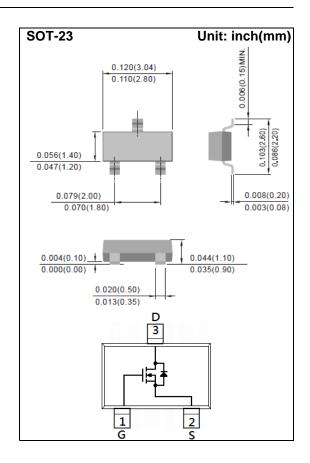
Voltage 40 V Current 4.3A

Features

- R_{DS(ON)}, V_{GS}@10V, I_D@4.3A<42mΩ
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@3.9A<51m\Omega$
- Advanced Trench Process Technology
- Specially Designed for switch Load, PWM applications, and solid-state relays relay
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	40	V	
Gate-Source Voltage		V _{GS}	<u>+</u> 20		
Continuous Drain Current		I _D	4.3		
Pulsed Drain Current (Note 4)		I _{DM}	17.2	A	
Power Dissipation	T _a =25°C	P _D	1.25	W	
	Derate above 25°C		10	mW/°C	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance					
- Junction to Ambient (Note 3)		R _{θJA}	100	°C/W	



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	40	-	-	.,,	
Gate Threshold Voltage	$V_{GS(th)}$	GS(th) VDS=VGS, ID=250uA		1.5	2.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =4.3A	-	35	42	mΩ	
		V _{GS} =4.5V, I _D =3.9A	-	44	51		
Zero Gate Voltage Drain Current	IDSS	V _{DS} =40V, V _{GS} =0V	-	-	1	uA	
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 5)							
Total Gate Charge	Q_g		-	4.8	-		
Gate-Source Charge	Qgs	V _{DS} =20V, I _D =4.3A,	-	1.4	-	nC	
Gate-Drain Charge	Q_{gd}	V _{GS} =4.5V (Note 1,2)	-	1.8	-		
Input Capacitance	Ciss	.,	-	410	-	pF	
Output Capacitance	Coss	V _{DS} =20V, V _{GS} =0V,	-	50	-		
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	30	-		
Turn-On Delay Time	td _(on)	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	-	4	-		
Turn-On Rise Time	tr	V _{DD} =20V, I _D =3.5A,	-	30	-	ns	
Turn-Off Delay Time	td _(off)	V _{GS} =10V, R _G =1Ω (Note 1,2)	-	15	-		
Turn-Off Fall Time	tf	KG=112 (Note 1,2)	-	8	-		
Drain-Source Diode							
Maximum Continuous Drain-Source					4.0	Δ.	
Diode Forward Current	Is		-	-	1.0	Α	
Diode Forward Voltage	V _{SD}	Is=1.0A, V _G s=0V	-	0.78	1.2	V	
Reverse Recovery Time	trr	V _{GS} =0V, I _S =3.5A	-	10.2	-	ns	
Reverse Recovery Charge	Qrr	dl _F / dt=100A/us	-	5.5	-	nC	

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

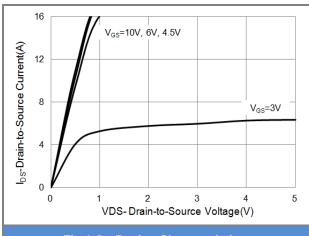


Fig.1 On-Region Characteristics

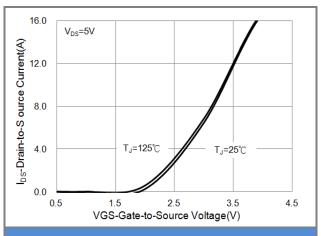


Fig.2 Transfer Characteristics

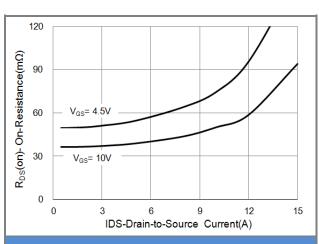


Fig.3 On-Resistance vs. Drain Current

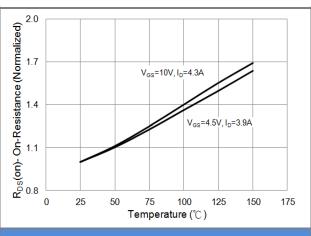
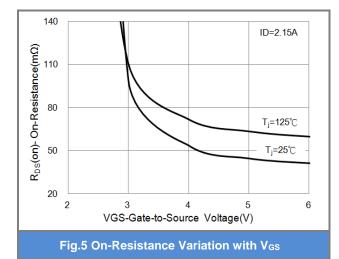
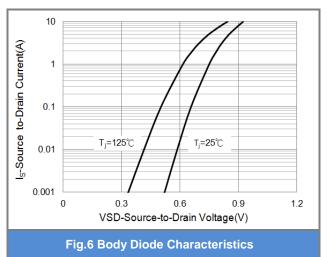


Fig.4 On-Resistance vs. Junction temperature







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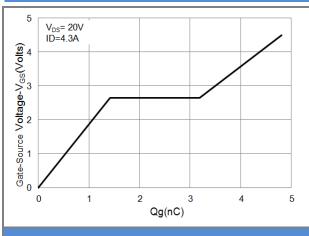


Fig.7 Gate-Charge Characteristics

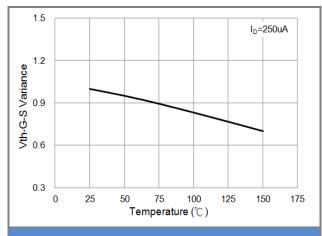


Fig.8 Threshold Voltage Variation with Temperature

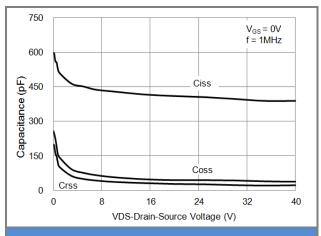


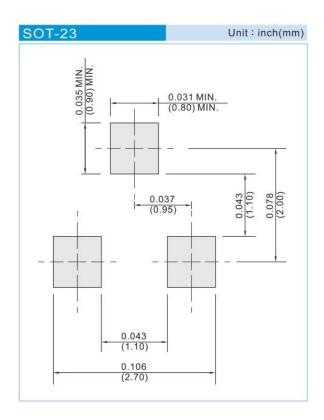
Fig.9 Capacitance vs. Drain-Source Voltage



Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJA3440-AU	SOT-23	3K pcs / 7" reel	A40

Mounting Pad Layout





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